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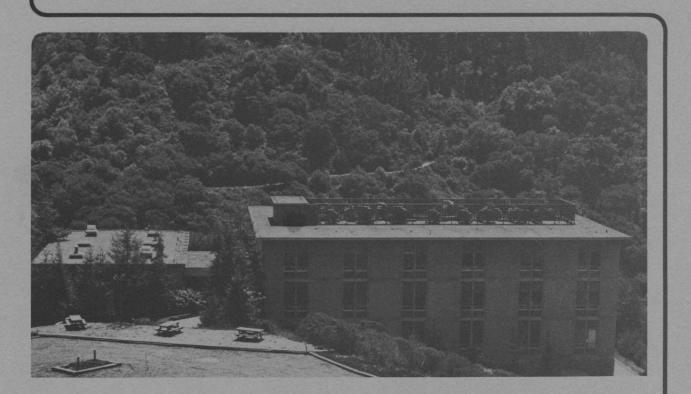
## Materials & Chemical Sciences Division

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### ELECTRICAL PROPERTIES OF HIGH T SUPERCONDUCTORS UNDER HIGH PRESSURES

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ELECTRICAL PROPERTIES OF HIGH T<sub>c</sub> SUPERCONDUCTORS UNDER HIGH PRESSURES

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Pressure has played a significant role in the recent developments of high transition temperature ( $T_c$ ) superconductors. Chu and coworkers<sup>1,2</sup> found very early on that the  $T_c$  in LaBaCuO compounds increased with pressure with a rather large coefficient of  $dT_c/dP$  of 9 K/GPa. These results led Chu and coworkers to substitute Ba with Sr<sup>1</sup> and later replace La with Y.<sup>3</sup> In both cases they found that  $T_c$  increased as a result of the substitution. The large pressure coefficients of  $T_c$ in these materials also posed a stringent test of any theories attempting to explain the superconductivity in these materials. Here we report electrical resistance measurements in these new superconductors at pressures up to 16 GPa.

Our measurements were performed on single-phase but polycrystalline samples of La<sub>1.85</sub>Ba<sub>0.15</sub>CuO<sub>4</sub>, La<sub>1.85</sub>Sr<sub>0.15</sub>CuO<sub>4</sub> and YBa<sub>3</sub>Cu<sub>4</sub>O<sub>7.5</sub>. The samples were typically small fragments of about 200 microns across obtained by crushing larger pellets which have been characterized by xray, resistivity and magnetic susceptibility measurements at ambient pressure. Quasi-hydrostatic pressure was applied with a diamond anvil high pressure cell. The technique for loading the sample into the cell

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for electrical measurements have been described elsewhere.<sup>4</sup> The sample was surrounded by  $CaSO_4$  powder as the pressure medium and the pressure was determined by the standard ruby fluorescence technique.<sup>4</sup> Diamond anvils of three different sizes have been utilized to cover these three pressure ranges: 0-5 GPa, 2-10 GPa and 3-20 GPa. The resistance of the sample was determined by a quasi-four-probe technique via two loops of copper wires.<sup>4</sup> Electrical contact between the copper wire and the sample was achieved by pressure. This contacting procedure was probably responsible for the residual resistance found in some of our samples below T<sub>c</sub>. Since this residual resistance was independent of pressure it did not affect our accuracy in determining T<sub>c</sub>.

Figure 1(a) shows the room temperature pressure dependence of the resistance R in La<sub>1.85</sub>Sr<sub>0.15</sub>CuO<sub>4</sub> and YBa<sub>3</sub>Cu<sub>4</sub>O<sub>7.5</sub>. In case of LaSrCuO we found very little change in R with pressure until about 7 GPa. At about 7 GPa R started to decrease rapidly with pressure and at the same time the superconducting transition in the R vs T curve started to disappear. Such sudden change in R and the disappearance of the superconducting transition can be explained by pressure induced phase transitions. Although x-ray diffraction studies in the LaSrCuO compounds observed no phase transition up to 20 GPa,<sup>5</sup> the possiblility of an electronic phase transitions could not be ruled out. In YBaCuO R showed a similar decrease at around 4 GPa. In this case R decreased by about two orders of magnitude between 4 and 6 GPa which can only be accounted for by a phase transition. In addition R showed another smaller abrupt decrease around 9 GPa. When the pressure was released from 16 GPa we found that the resistance remained unchanged at a relatively low value indicating that the sample has been permanently altered, possibly due to conversion

into a low resistance metastable phase.

Figure 1(b) shows the pressure dependence of the superconducting transition temperature T<sub>c</sub> in LaBaCuO and LaSrCuO. We have defined  $T_{\rm c}$  as the temperature corresponding to the mid-point of the resistance drop associated with the superconducting transition. Earlier experiments have shown rapid increases in T<sub>c</sub> with pressure up to only 2 GPa. 1,6-8 Below 2 GPa we found that Tc increased with an average rate of about 2.5 K/GPa in LaSrCuO. Between 2 and 4 GPa this rate decreased to less than 1 K/GPa. Between 4 and 6 GPa T<sub>c</sub> remained almost constant at the maximum value of ~46.3 K. The results in LaBaCuO is qualitatively similar to LaSrCuO with T, showing a tendency to saturate at higher pressures. Qualitatively the pressure dependence of T, in LaSrCuO is very similar to that of La<sub>2</sub>S<sub>4</sub> reported by Filing et al. In the latter case it has been shown that the initial increase in T<sub>c</sub> with pressure was due to increase in the densityof-states in the Fermi level induced by pressure. The subsequent decrease in T<sub>c</sub> at higher pressure was due to decrease in the electron-phonon interaction as the phonons were hardened by pressure. Since the mechanisms responsible for superconductivity in the high T<sub>c</sub> materials are still unclear, it would be premature to interpret our results with conventional theory based on electron-phonon interactions.

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#### FIGURE CAPTION

